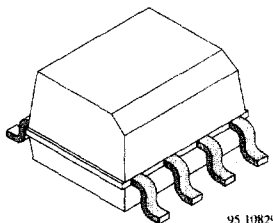


## Surface Mount Optocoupler with Phototransistor Output

Order Nos. and Classification table is on sheet 2.

### Description

The MOC series consists of a phototransistor optically coupled to a gallium arsenide infrared emitting diode in an 8-lead plastic dual inline packages (small outline).



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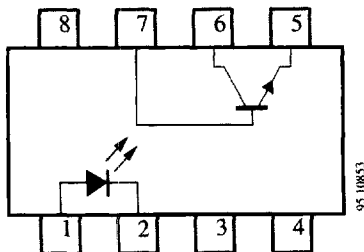
### Applications

- Computer-peripheral interface
- Microprocessor system interface
- Low power DC/DC converter
- Hybride substrates that require high density mounting

### Features

- Current Transfer Ratio (CTR) selected into 3 groups, specified at  $I_F = 1 \text{ mA}$
- MOC215 minimum 20%
- MOC216 minimum 50%
- MOC217 minimum 100%
- Test isolation voltage between input and output  $V_{IO} \text{ (RMS): } 2.5 \text{ kV}$
- 8-lead package, similar to SOIC-8
- Minimum  $V_{(BR)CEO}$  of 90 V guaranteed
- Soldering methods according to CECC 00802 table 1, class B or C
- Low temperature coefficient of CTR
- Base connected
- Suitable for cleaning process without chemical solvent

### Pin Connection



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## Order Schematic

| Part Numbers        | CTR-Ranking         |
|---------------------|---------------------|
| MOC215/ MOC215-GS12 | >20% <sup>1)</sup>  |
| MOC216/ MOC216-GS12 | >50% <sup>1)</sup>  |
| MOC217/ MOC217-GS12 | >100% <sup>1)</sup> |

Suffix: GS12 = Taped and reeled version

<sup>1)</sup>  $I_F = 1 \text{ mA}$

## Absolute Maximum Ratings

### Input (Emitter)

| Parameters            | Test Conditions                 | Symbol    | Value | Unit             |
|-----------------------|---------------------------------|-----------|-------|------------------|
| Reverse voltage       |                                 | $V_R$     | 5     | V                |
| Forward current       |                                 | $I_F$     | 60    | mA               |
| Forward surge current | $t_p \leq 10 \mu\text{s}$       | $I_{FSM}$ | 3     | A                |
| Power dissipation     | $T_{amb} \leq 25^\circ\text{C}$ | $P_{tot}$ | 100   | mW               |
| Junction temperature  |                                 | $T_J$     | 125   | $^\circ\text{C}$ |

### Output (Detector)

| Parameters                | Test Conditions                       | Symbol    | Value | Unit             |
|---------------------------|---------------------------------------|-----------|-------|------------------|
| Collector base voltage    |                                       | $V_{CBO}$ | 90    | V                |
| Collector emitter voltage |                                       | $V_{CEO}$ | 90    | V                |
| Emitter collector voltage |                                       | $V_{ECO}$ | 7     | V                |
| Collector current         |                                       | $I_C$     | 50    | mA               |
| Collector peak current    | $t_p/T = 0.5, t_p \leq 10 \text{ ms}$ | $I_{CM}$  | 100   | mA               |
| Power dissipation         | $T_{amb} \leq 25^\circ\text{C}$       | $P_{tot}$ | 150   | mW               |
| Junction temperature      |                                       | $T_J$     | 125   | $^\circ\text{C}$ |

### Coupler

| Parameters                      | Test Conditions                    | Symbol    | Value       | Unit             |
|---------------------------------|------------------------------------|-----------|-------------|------------------|
| AC isolation test voltage (RMS) |                                    | $V_{IO}$  | 2.5         | kV               |
| Total power dissipation         | $T_{amb} \leq 25^\circ\text{C}$    | $P_{tot}$ | 250         | mW               |
| Ambient temperature range       |                                    | $T_{amb}$ | -55 to +100 | $^\circ\text{C}$ |
| Storage temperature range       |                                    | $T_{stg}$ | -55 to +125 | $^\circ\text{C}$ |
| Soldering classification        | Single wave, $t \leq 10 \text{ s}$ | $T_{sd}$  | 260         | $^\circ\text{C}$ |

<sup>1)</sup> Related standard climate 23/50 DIN 50014

**Electrical Characteristics**

**Input (Emitter)**

| Parameters           | Test Conditions                 | Symbol     | Min. | Typ. | Max. | Unit |
|----------------------|---------------------------------|------------|------|------|------|------|
| Forward voltage      | $I_F = 50 \text{ mA}$           | $V_F$      |      | 1.25 | 1.6  | V    |
| Breakdown voltage    | $I_R = 100 \text{ }\mu\text{A}$ | $V_{(BR)}$ | 5    |      |      | V    |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$    | $C_j$      |      | 50   |      | pF   |

**Output (Detector)**

| Parameters                          | Test Conditions                         | Symbol        | Min. | Typ. | Max. | Unit |
|-------------------------------------|---|---------------|------|------|------|------|
| Collector base breakdown voltage    | $I_C = 100 \text{ }\mu\text{A}$         | $V_{(BR)C80}$ | 90   |      |      | V    |
| Emitter collector breakdown voltage | $I_C = 1 \text{ mA}$                    | $V_{(BR)CEO}$ | 90   |      |      | V    |
| Emitter collector breakdown voltage | $I_E = 100 \text{ }\mu\text{A}$         | $V_{(BR)ECO}$ | 7    |      |      | V    |
| Collector emitter cut-off current   | $V_{CE} = 10 \text{ V}, I_f = 0, E = 0$ | $I_{CEO}$     |      |      | 50   | nA   |

**Coupler**

| Parameters                           | Test Conditions   | Symbol      | Min. | Typ. | Max. | Unit |
|--------------------------------------|---|-------------|------|------|------|------|
| AC isolation test voltage (RMS)      | $f = 50 \text{ Hz}, t = 1 \text{ s}$                                  | $V_{IO}$    | 2.5  |      |      | kV   |
| Collector emitter saturation voltage | $I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$                             | $V_{CEsat}$ |      |      | 0.3  | V    |
| Cut-off frequency                    | $I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}, R_L = 100 \text{ }\Omega$ | $f_C$       |      | 110  |      | kHz  |
| Coupling capacitance                 | $f = 1 \text{ MHz}$   | $C_k$       |      | 0.3  |      | pF   |

**Current Transfer Ratio (CTR)**

| Parameters | Test Conditions                             | Type   | Symbol | Min. | Typ. | Max. | Unit |
|------------|---|--------|--------|------|------|------|------|
| $I_C/I_F$  | $V_{CE} = 10 \text{ V}, I_F = 1 \text{ mA}$ | MOC215 | CTR    | 0.2  | 0.5  |      |      |
|            |   | MOC216 | CTR    | 0.5  | 1    |      |      |
|            |   | MOC217 | CTR    | 1    | 2    |      |      |

## Switching Characteristics (Typical Values)

$V_S = 10\text{ V}$

| Type                | $R_L = 100\ \Omega$ (see figure 1) |                    |                       |                    |                    |                       |                  |
|---------------------|------------------------------------|--------------------|-----------------------|--------------------|--------------------|-----------------------|------------------|
|                     | $t_d[\mu\text{s}]$                 | $t_r[\mu\text{s}]$ | $t_{on}[\mu\text{s}]$ | $t_s[\mu\text{s}]$ | $t_f[\mu\text{s}]$ | $t_{om}[\mu\text{s}]$ | $I_C[\text{mA}]$ |
| MOC215/ MOC215-GS12 | 0.90                               | 1.10               | 2.00                  | 0.10               | 1.80               | 1.90                  | 2                |
| MOC216/ MOC216-GS12 | 1.60                               | 1.80               | 3.40                  | 0.10               | 2.60               | 2.70                  | 2                |
| MOC217/ MOC217-GS12 | 2.20                               | 2.80               | 5.00                  | 0.20               | 4.10               | 4.30                  | 2                |

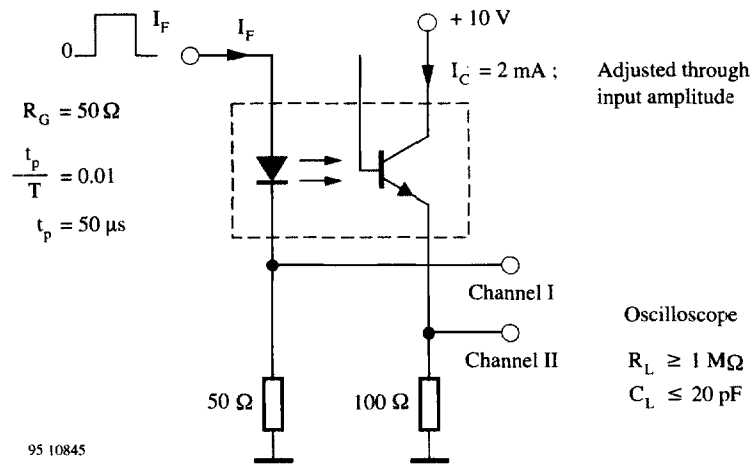


Figure 1. Test circuit, non-saturated operation

**Typical Characteristics** ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

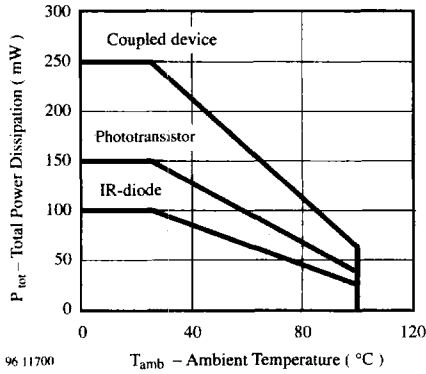


Figure 1. Total Power Dissipation vs. Ambient Temperature

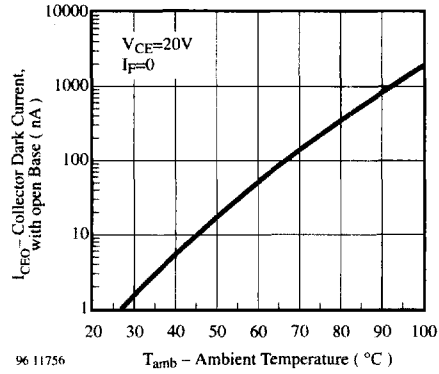


Figure 4. Collector Dark Current vs. Ambient Temperature

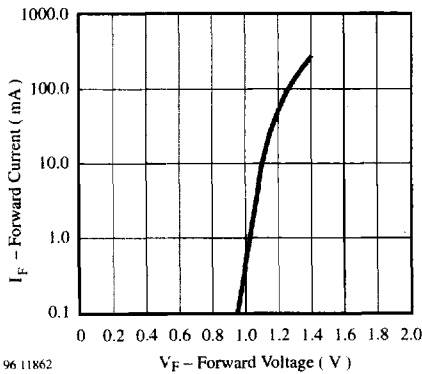


Figure 2. Forward Current vs. Forward Voltage

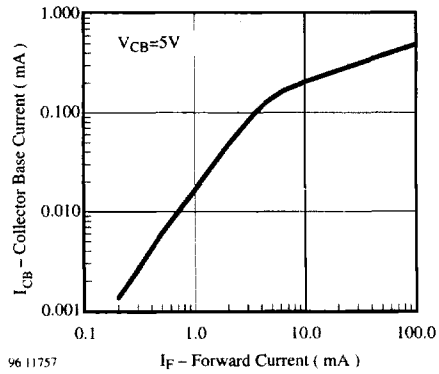


Figure 5. Collector Base Current vs. Forward Current

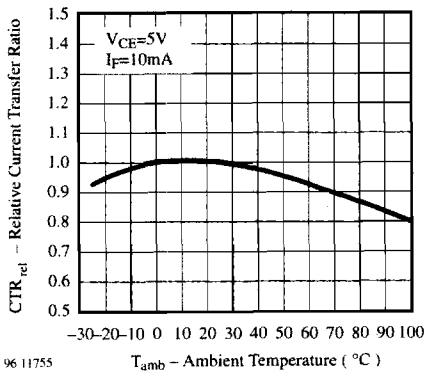


Figure 3. Rel. Current Transfer Ratio vs. Ambient Temp.

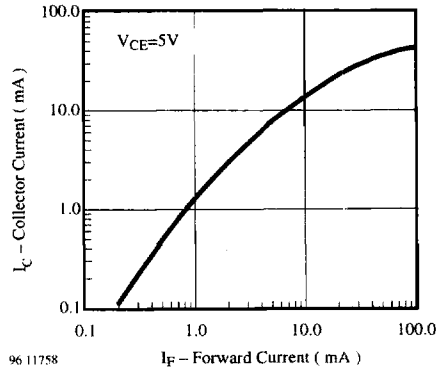


Figure 6. Collector Current vs. Forward Current

## Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

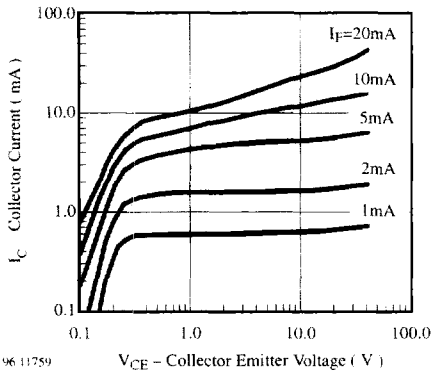


Figure 7. Collector Current vs. Collector Emitter Voltage

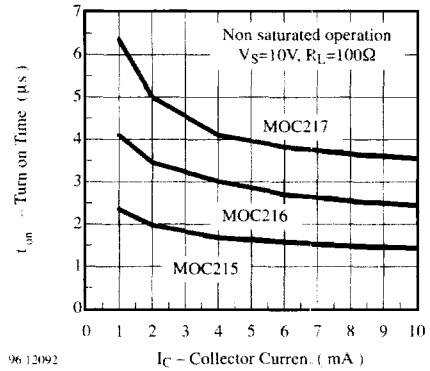


Figure 10. Turn on Time vs. Collector Current

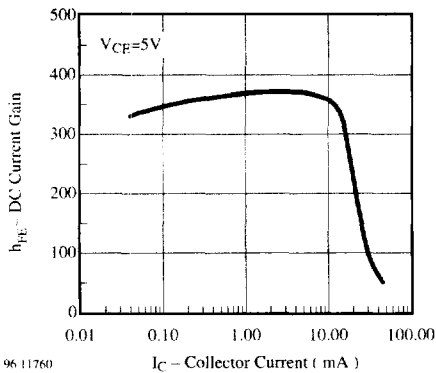


Figure 8. DC Current Gain vs. Collector Current

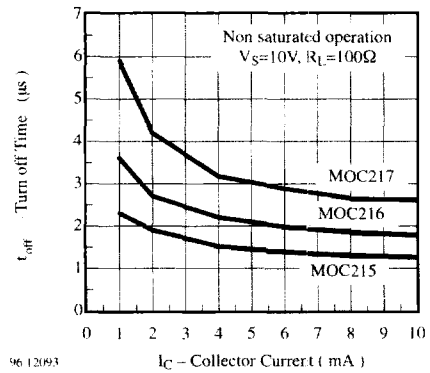


Figure 11. Turn off Time vs. Collector Current

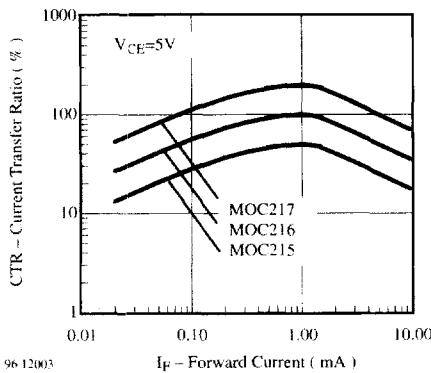
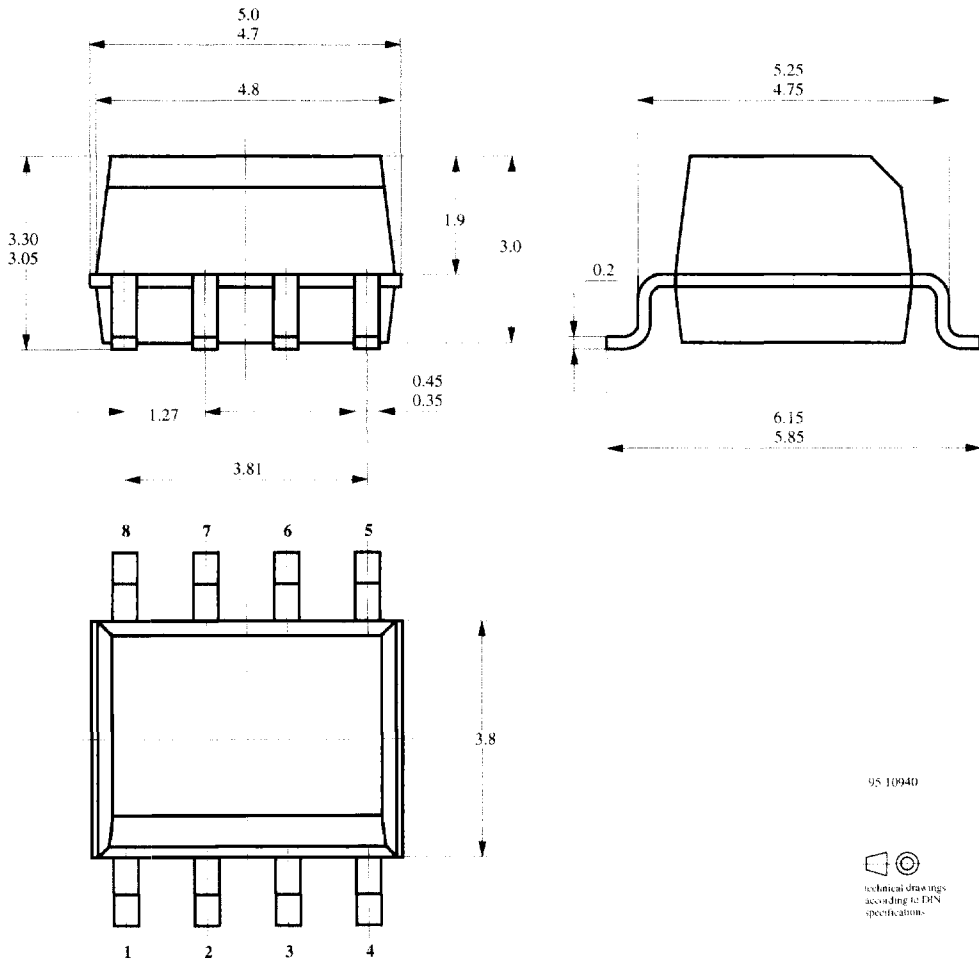


Figure 9. Current Transfer Ratio vs. Forward Current

**Dimensions in mm**



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technical drawings  
according to DIN  
specification